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**DIFFUSION BONDED SPUTTERING TARGET ASSEMBLY
WITH PRECIPITATION HARDENED BACKING PLATE
AND METHOD OF MAKING SAME**

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BACKGROUND OF THE INVENTION

The present invention relates to a sputtering target assembly having a precipitation hardened backing plate diffusion bonded to a sputtering target.

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There has been growing interest in sputtering target assemblies with increasingly thin sputtering targets to reduce costs and, in some cases, accommodate the sputtering target assembly in certain sputtering chambers. In such applications, sputtering target assemblies of less than about one inch total thickness may be required. However, with such sputtering target assemblies, the strength of the backing plate may be exceeded under the conditions encountered in the sputtering chamber, which may include high water pressure on one side for cooling and high vacuum on the other side during the sputtering process. Thermal cycling and pressure resulting from circulating coolant exerted upon the backside of the target assembly with simultaneous vacuum conditions on the front face of the target can result in elastic and plastic deformation of the target backing plate assembly.

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Although sputtering target assemblies may be made by solder bonding backing plates of various materials to a target, solder bonding has the disadvantage of not being able to withstand high power sputtering applications. Thus, diffusion bonded sputtering target assemblies are preferred.

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The present invention provides a method of making a sputtering target assembly with a high strength backing plate diffusion bonded to a sputtering target that can withstand the stresses and strains typically encountered in sputtering chambers.

SUMMARY OF THE INVENTION

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According to the invention there is provided a method of making a heat treated sputtering target assembly that comprises providing a sputtering target and a heat treatable, precipitation hardenable backing plate diffusion bonded to the sputtering target wherein the diffusion bonded sputtering target assembly is heat treated to precipitation harden the backing plate without delaminating or degrading the diffusion bond between target and backing plate. The method comprises precipitation hardening the backing plate by heat treatment that includes quenching the diffusion bonded sputtering target assembly by the process includes heating, working, and quenching and the quenching is performed after diffusion bonding by immersing the sputtering target assembly in a quenchant to immerse the backing plate without submerging the sputtering target. The sputtering target assembly may be subjected to

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a plurality of precipitation hardening treatments that include heating and partial-immersion quenching, as described, to provide a desired temper in the backing plate. In a preferred embodiment, the backing plate comprises a heat treatable aluminum alloy of the 2000, 6000 or 7000 series and the sputtering target comprises aluminum, titanium, or nickel, titanium-tungsten, tungsten, cobalt and tantalum and alloys thereof. The sputtering target assembly of the invention comprises a precipitation hardened backing plate diffusion bonded to a sputtering target.

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DETAILED DESCRIPTION

A problem encountered in producing diffusion bonded sputtering target assemblies is difficulty in producing a sputtering target assembly having a precipitation hardened backing plate, e.g. a backing plate in the fully hardened condition. For example, diffusion bonded sputtering target assemblies may be produced with the flange in an annealed, e.g. fully annealed, condition or in a condition below the desired degree of hardening, with the result that optimal mechanical strength of the sputtering target assembly is not developed and the assembly may be deformed during service. An example of a sputtering target assembly system particularly vulnerable to this problem is an assembly with an aluminum alloy backing plate which softens upon exposure to elevated temperature encountered during the diffusion bonding process. Although aluminum alloys are capable of being heat treated to achieve high strength, such as by heat treating to the T6 hardened condition, such heat treatments include quenching steps that would render the diffusion bonded assembly vulnerable to delamination and/or other degradation of the diffusion bond.

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To illustrate one embodiment of the invention, described below is an example of producing a diffusion bonded sputtering target assembly comprising a heat treatable aluminum alloy diffusion bonded to a sputtering target. A heat treatable material, e.g. aluminum alloy, is defined as a material containing constituents that have increased solubility at elevated temperatures, with restricted solubility at lower temperature. Although this example is of a heat treatable aluminum alloy, it is apparent that the process may be usefully applied to backing plates of other precipitation hardenable materials such as alloys of titanium, copper, or aluminum (e.g. Ti alloys, Cu alloys, Al alloys). Similarly, various target materials may be employed, such as titanium, aluminum, nickel, tungsten, titanium-tungsten, tantalum, cobalt, and alloys thereof. Typically, diffusion bonded titanium targets are produced by bonding aluminum or aluminum alloy backing plates in a fully annealed condition to a target. The diffusion bond is created by heating to elevated temperatures in excess of about 300°C which is sufficiently high to bring the aluminum or aluminum alloy backing plate into a dead soft state. However, by the method of the invention the sputtering

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target assembly is processed to bring the backing plate into a hardened condition. In the case of aluminum alloys, for example, commercially heat treatable aluminum alloys, such as alloys of aluminum in the 2000, 6000 and 7000 series, can be processed to produce high strength but without causing target deformation in the sputtering target assembly or delamination during use.

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In one example, a sputtering target assembly is made using as a backing plate heat treatable aluminum alloy-6061. This commercial alloy has a purity of typically about 99.0 to 99.9 wt.% with the primary alloy constituents comprising silicon, about 0.4 to 0.8 wt.%, magnesium about 0.8 to 1.2 wt.%, and iron about 0.7 wt.%. The primary strengthening precipitate in a 6000 series aluminum is Mg_2Si .

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Advantageously, a two-stage heat treatment is used, including a solution treatment followed by a secondary artificial aging step to allow control over the precipitation of the Mg_2Si , thus promoting increased mechanical properties. Generally, precipitation strengthening of super saturated solid solution involves the formation of finely dispersed precipitates during aging heat treatments. An important aspect of both solution treatment, i.e., obtaining a super saturated solid solution, and the artificial aging heat treatment is quenching.

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Precipitation hardening, also referred to as age hardening, involves precipitation of second phase from a super saturated solid solution. The precipitates impede movement of dislocations which makes the alloy stronger and less ductile. In order for an alloy to be precipitation hardenable; it must display partial solid solubility and decreasing solid solubility with decreasing temperatures. Precipitation hardening comprises dissolving, or "solutioning", which requires heating above this solvus temperature in order to form a homogenous solid solution, and quenching rapidly to room temperature to retain a maximum amount of alloying elements in solid solution followed by an aging step, i.e., heating the alloy below the solvus to permit precipitation of fine particles of a second phase. The solvus represents the boundary on a phase diagram between the solid-solution region and a region comprising a second phase in addition to the solid solution. During heat treatment of these alloys a controlled dispersion of submicroscopic particles is formed in the microstructure and the final properties of the alloy depend upon how the particles are dispersed and upon their size and stability.

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A diffusion bonded target assembly often combines materials of different Coefficient of Thermal Expansion (CTE). Rapid cooling of such a system could cause partial distortion and separation of the bonded materials. By practicing the process of the invention, diffusion bonding is combined with heat treatment to produce a backing plate with the desired temper e.g. T6 temper in AL-6061. This accommodates the mismatch of the Coefficient of Thermal

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Expansion of the target and backing plate and avoids bond failure.

5 As an example, material to be used as the sputtering target is provided and prepared for diffusion bonding by cleaning the surface to be bonded to the backing plate. The surface may be prepared by machining one continuous channel creating a spiral pattern on the surface to be bonded followed by grit blasting and chemical cleaning. The material to be used as the backing plate, e.g. as cast homogenized aluminum 6061 billet or alternate heat treatable alloy, or work hardened material, is cut to length (based on desired target 10 configuration ending volume and overall dimension) preheated to a temperature sufficient to decrease the flow stress, hot forged with forge platens at room temperature or elevated to the same temperature as the part to be forged, and quenched by full submersion into quenchant, e.g. water, to produce a work hardened AL-6061 alloy backing plate. The backing plate is then annealed to remove work hardening effects of forging and the surface of the backing 15 plate to be bonded to the target is then prepared and cleaned, e.g. by machining, milling or turning on a lathe. The target and backing plate are assembled by mating the described prepared surfaces and diffusion bonded by first preheating the assembly to a temperature sufficient to decrease the flow stress of the backing plate and promote full intimate contact of the prepared surfaces during the forging step, and hot forging. The forge platens may once 20 again be heated to an elevated temperature and a pressure of about 20,000 psi to 35,000 psi is applied to the target/backing plate assembly to allow full contact of mated bond surfaces. The forged assembly is then heat treated by placing the assembly directly into a preheated furnace. The heat treatment is designed to produce a desired temper, e.g. T6 for alloy 6061, to harden and strengthen the backing plate material. The heat treatment comprises solution 25 treating the backing plate by heating the diffusion bonded sputtering target assembly to a temperature of at least about 985°F, holding the assembly at a temperature for a time sufficient to dissolve the second phase into solution, and then quenching. The heat treated sputtering target assembly is quenched by partially immersing the assembly in a quenchant, e.g. water, so that the backing plate is submerged without submerging the target. By 30 quenching in this manner the backing plate acts as a heat sink to remove heat from the target and maintains the integrity of the diffusion bond.

The quenched diffusion bonded sputtering target assembly may then be machined and flattened after which it can be artificially aged to precipitation harden the backing plate to a hardened tempered condition, e.g. by heating to temperature and holding a sufficient time to 35 precipitate the second phase in the aluminum matrix followed by partially-immersed quenching as described above by immersing in the quenchant to submerge the backing plate without submerging the target or allowing the assembly to cool in air, i.e. quenching allows rapid process cycle times. The resulting sputtering target assembly comprises a precipitation

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hardened backing plate, such as Al 6061, having the desired temper, e.g. T6, diffusion
bonded to the target. It is evident that the process may be adjusted to produce a backing plate
5 of any desired temper, e.g. 0, T₄, etc., but without adversely affecting the diffusion bond
between the target and backing plate.

The shear strength for a diffusion bonded sputtering target assembly made with non-
heat treatable aluminum alloy is generally in the range of about 12,000 psi to 20,000 psi with
the average being toward a value of 16,000 psi. A sputtering target assembly of aluminum
10 alloy 6061-T6 has a bond shear strength in the range of about 16,000 to 23,000 psi at room
temperature and about 17,700 psi at 392°F. As indicated previously, the process is also
capable of producing sputtering target assemblies having backing plates with other temper
properties, e.g. T₄, as well. The following are mechanical and physical properties of
particular sputtering target assemblies:

15 A. Shear Strength, Titanium to Aluminum bond strength.

70°F (21°C): 16 Ksi to 23 Ksi (151 MPa to 158 MPa)

392°F (200°C): 17.7 Ksi (122 MPa)

B. Ultimate Tensile Strength of backing plate.

20 70°F (21°C): 45 Ksi (310 MPa)

C. Yield Strength, the *Elastic Limit*.

70°F (21°C): 36 Ksi (248 Mpa)

D. Hardness of the finished backing plate: 100-109 HBW.

25 E. Titanium grain structure is unaltered by the diffusion bonding and
6061-T6 processing steps.

For comparison purposes, the following are 6061 commercial aluminum alloy
Temper designations used to identify thermally enhanced mechanical properties:

30 "T6", typical commercial properties:

Ultimate Tensile Strength of 45ksi (310 MPa)

Hardness of 95 HBW (Brinell Number)

"T4", typical commercial properties:

Ultimate Tensile Strength of 35ksi (241 Mpa).

35 Hardness of 65 HBW.

Mechanical properties are typically measured by tensile testing in conformance with
ASTM E8-89b or ASTM B557-94. Hardness is measured in Brinell Number-HB, 500 Kg
load, 10 mm ball in conformance to ASTM E 10-93.

Sputtering target assemblies with 6061 aluminum is presently preferred in the T6 temper condition which produces a typical ultimate tensile stress of about 45ksi (310 Mpa) in a hardness of about 95 Brinell Number.

The process described above combines a diffusion bonding with a two-stage heat treatment found to be desirable to generate T6 properties. Tempering of 6061 aluminum involves an initial solution treatment followed by a secondary artificial aging step. The two-step heat treating controls the precipitation of Mg_2Si to promote an increase in strength. A general requirement for precipitation strengthening of super saturated solid solution involves formation of finely dispersed precipitates during aging heat treatments. The particularly described quenching technique, after the solution treatment, is very important to achieve the desired mechanical properties without adversely affecting the diffusion bond of the target to the backing plate. Commercial grade aluminum 6061 can be purchased in the T6 condition and annealed to a 0 temper for subsequent processing, work hardened material can be used as the backing plate starting material, or homogenized 6061 billet of suitable cast diameter can be used eliminating backing plate preheat and forge steps. Table 1 below compares the properties of sputtering target assemblies produced by three different methods identified in the table as Ti-6061-1, -2, and -3. The first target is produced by standard diffusion bonding practices described above followed by artificial age hardening and water quenching. The second assembly is produced by diffusion bonding and includes solution treatment of alloy 6061 followed by a water quench and then a secondary artificial age hardening with a full water quench. The third process is by diffusion bonding the assembly, solution treatment of the alloy 6061 followed by a partial immersed water quench, then performing secondary artificial age hardening and again followed by a partial immersed water quench. All three samples were processed through Ultrasound Bondline Scan practices and then sectioned in half for macro examination of the bondline. Samples were taken for shear testing, hardness and metallography.

Table 1: Phase One, half scale target evaluation data.

Target	C-Scan	Hardness, HB	Shear Strength, psi
Ti-6061-1	100%	42.4	15,150
Ti-6061-2	99%	109	17,615
Ti-6061-3	99%	100	19,021

No delamination of target and backing plate was noted during processing which was confirmed by metallography. The process for Ti-6061-2 also produced acceptable results,

however, upon evaluation of shear strength values and bondline metallurgy implies the full quench may create a negative impact on bondline integrity, but may be employed where target and backing plate material form adequate intermetallic bonding.

Table 2 reports results of examples of full scale titanium blank used in conjunction with an alloy 6061 backing plate to produce a diffusion bonded target. The practice previously described for material surface preparation of the target and backing plate and the processing described above for the Ti-6061-3 assembly was used. Shear samples were prepared and analyzed for conformance to MIL-J-24445A(SH), Triple Lug configuration. The results of shear testing are shown in Table 2.

Table 2: Phase Two Shear Strength, Triple Lug Shear testing performed at room temperature and 200°C.

Sample	Lug	Temp. (°C)	Load, lbs.	Shear Stress, psi	Average
1	A	21	4657	24,739	23,535
	B	21	3432	19,124	
	C	21	4916	26,744	
2	A	21	3830	21,681	22,678
	B	21	3872	20,879	
	C	21	4703	25,472	
3	A	200	2778	15,309	17,727
	B	200	3472	18,622	
	C	200	3474	19,251	

The average diffusion bond Shear Stress at room temperature is in the range of about 22.6 to 23.5 ksi. Elevated temperature testing at 200°C showed a value of about 17.7 ksi, both of which exceed the nominal Shear Stress of standard backing plate materials when tested at room temperature.

Metallography examination showed no significant loss of diffusion bonding due to change in chemistry or metallurgy of the 6061 aluminum as compared with non-precipitation hardenable aluminum alloy backing plates. After flattening and machining, scanning of the target in a T6 condition and rough machined condition showed a 99.99% bonded area. The results of mechanical testing are shown in Table 3 below. Tensile testing coupons and methods were conducted under ASTM E8 and B557 standards. Estimates of Young's Modulus were measured from stress/strain curves of the tensile test as outlined in ASTM

E111-82 and hardness testing was performed per ASTM E10-93. The results in Table 3 compare titanium diffusion bonded targets to 6061-T6 Aluminum backing plate target, 6061 Aluminum in the 0 temper, and an aluminum alloy backing plate containing 1% Si and 0.5% Cu taken from a typical diffusion bonded target. The 6061 backing plate meets typical industry standards for 6061 in the T6 condition.

Table 3: Phase Two mechanical data compared to published values of 6061 and alternate backing plate aluminum alloy.

Material	Source	Ultimate Stress, ksi	Yield Stress, ksi	Elong., % (1/2" dia. sample)	Modulus, x10 ⁶ psi	Hardness, HB
6061-T6	Published	45.0	40.0	17.00	10.00	95
6061-0	Raw Material	20.8	7.7	24.33	10.03	38
6061-T6	Diffusion Bonded T6	43.8	41.5	11.00	10.90	96
A1+1% Si+0.5% Cu	Alternate A1 Alloy	15.7	7.0	39.33	N/A	29

A preferred embodiment to manufacture a sputtering target assembly with a precipitation hardenable backing plate diffusion bonded to a sputtering target is illustrated below by the process described for producing an Aluminum 6061 Alloy backing plate diffusion bonded to a titanium sputtering target.

Continuously cast 6061 homogenized billet is cut to specified lengths corresponding to the final dimensions of the target to be diffusion bonded. The diameter of the billet can be in the range of about seven to twenty-four inches depending on the diameter of the target.

The 6061 billet is pre-heated to a range of 500°F to 750°F and allowed to sustain temperature for about twenty to thirty minutes. The billet is then forged to a designated height and quenched. The forge used for this application is advantageously capable of a minimum of about 10,000 psi applied pressure and fashioned with a heated platen for isothermal condition. The forge rate is in the range of about three to ten inches per minute. The result is a backing plate in a roughed condition.

The backing plate is then annealed to remove any effects of working in the backing plate manufacturing step by heating the plate to a temperature of about 775°F for a minimum of three hours. After the three hour soak at 775°F, the temperature is reduced 500°F at a rate of about 50°F per hour. Upon reaching temperature of 500°F, it is allowed to cool in air to

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room temperature. An alternative is to use a cast homogenized 6061 billet of suitable diameter, no forge or anneal step is required.

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The target and backing plate are diffusion bonded after the surfaces to be bonded have been prepared and cleaned. For example, the target surface can be prepared and cleaned by machining one continuous threaded channel on the surface, grit blasting the surface, and chemically cleaning the surface. The surface of the backing material can be cleaned by machining, milling or turning on a lathe. The backing plate and target is diffusion bonded by

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preheating to a temperature sufficient for adequate material flow and hot forged. After diffusion bonding, the diffusion bonded assembly is solution heat treated for a range of one to three hours, i.e. depending on assembly thickness, at 985°F to achieve to achieve a T4 condition. The time at temperature is determined by the target thickness, three hours being typical for a low profile target. The time is selected by applying 65 minutes for the first 1/2 inch and 30 minutes for each additional 1/2 inch increment. The diffusion bonded sputtering target assembly is quenched in a quenchant, e.g. a water tank, held at a temperature range of approximately 50°F to 110°F. To avoid delamination of the target from the backing plate, the assembly is only partially submerged in the quenchant, that is, the backing plate is immersed in the quenchant without submerging the target. Typically, the

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water is held to a maximum of about 1/2 inch from the top surface of the target phase and the assembly is allowed to cool. The target is then cut to a suitable rough diameter for further processing. It is possible that at this stage the diffusion bonded assembly may be bowed or distorted, and if so, the target will be high in the center. Such visual condition is corrected prior to final heat treatment by flattening using a hydraulic press, such as a 100 ton capacity press or greater. Tool steel plates may be placed over the target surface and the entire plate/assembly unit placed on a tool steel ring sized to the outer diameter of the target to allow for a plastic deformation that counters the bowed surface.

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The flattened assembly is artificially aged by heating at least 350°F for eight hours in an air furnace. The diffusion bonded sputtering target assembly is then quenched by the partial immersion quenching method described above. The assembly may also be air cooled if process times allow. The result of the process described is a sputtering target assembly in the T6 condition which can then be submitted to final machining.

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It is apparent from the foregoing that various changes and modifications may be made without departing from the invention. Accordingly, the scope of the invention should be limited only by the appended claims wherein what is claimed is:

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CLAIMS:

- 5 1. A method of making a heat treated sputtering target assembly comprising:
 provide a backing plate for a sputtering target;
 provide a sputtering target;
 diffusion bond the backing plate to the sputtering target to produce a sputtering
 target assembly; and
10 heat treat the sputtering target assembly to precipitation harden the backing
 plate of the diffusion bonded sputtering target assembly by a process that includes
 heating, and quenching wherein said quenching is performed by immersing the
 backing plate in a quenchant without submerging the sputtering target.
- 15 2. A method according to claim 1 further comprising flattening the quenched
 sputtering target assembly, artificially aging the backing plate and quenching by
 partially immersing the sputtering target assembly in a quenchant to submerge the
 backing plate without submerging the target or the assembly may be air cooled to
 achieve the desired hardness.
- 20 3. A method according to claim 1 wherein the backing plate has been work
 hardened prior to diffusion bonding to the sputtering target or a cast homogenized
 billet of suitable diameter may be used..
- 25 4. A method according to claim 3 wherein the backing plate of the sputtering
 target assembly is solution annealed prior to diffusion bonding.
- 30 5. A method according to claim 1 further comprising subjecting the sputtering
 target assembly to a plurality of precipitation hardening treatments that include heating
 and partial immersion quenching to provide a desired temper in the backing plate of
 the diffusion bonded sputtering target assembly.
- 35 6. A method according to claim 1 wherein the backing plate comprises a heat
 treatable alloy of titanium, aluminum or copper.
7. A method according to claim 1 wherein the backing plate comprises a heat
 treatable aluminum alloy of the 2000, 6000 or 7000 series.

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8. A method according to claim 1 wherein the quenchant is water.

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9. A method according to claim 1 wherein the sputtering target comprises aluminum, tungsten, nickel, titanium, titanium-tungsten, tantalum, cobalt, and alloys thereof.

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10. A heat treated sputtering target assembly comprising a precipitation hardened backing plate diffusion bonded to a sputtering target.

11. A sputtering target assembly according to claim 10 wherein the backing plate comprises a heat treatable alloy of titanium, aluminum or copper.

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12. A sputtering target assembly according to claim 10 wherein said backing plate comprises an aluminum alloy of the 2000, 6000 or 7000 series.

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13. A sputtering target assembly according to claim 10 wherein said sputtering target comprises aluminum, tungsten, nickel, titanium, titanium-tungsten, tantalum, cobalt, and alloys thereof.

14. A sputtering target assembly according to claim 10 wherein the backing plate is of various hardened tempered conditions 0, T4 and T6.

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15. A sputtering target assembly according to claim 10 wherein the backing plate has a T6 temper.

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This Sheet Has Been Replaced

